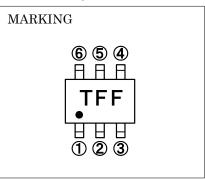
RT3TFFM

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION OUTLINE DRAWING Unit:mm RT3TFFM is a composite transistor built with 2.1RT1N431 chip and RT1P431 chip in SC-88 package. 1.25FEATURE T Silicon epitaxial type 0.65 Each transistor elements are independent. 2.0 Mini package for easy mounting 55 APPLICATION Inverted circuit, switching circuit, interface circuit, driver circuit **※**PNP built in transistor of "−"sign is abbreviation. 65 $0 \sim 0.1$ TERMINAL CONNECTOR RTr1 1:EMITTER1 2:BASE1 3:COLLECTOR2 R2RTr2 (4): EMITTER2 R25:BASE2 6:COLLECTOR1 **I**R1

MAXIMUM RATING (Ta= 25° C) (The characteristics apply to both Tr1 and Tr2.)

SYMBOL	PARAMETER	RATING	UNIT
Vcbo	Collector to Base voltage	50	V
VEBO	Emitter to Base voltage	10	V
VCEO	Collector to Emitter voltage	50	V
VIN	Input voltage	30	V
IC	Collector current	100	mA
ICM	Peak Collector current	200	mA
Pc	Collector dissipation (Total, Ta=25°C)	150	mW
Tj	Junction temperature	+150	°C
T_{stg}	Storage temperature	-55~+150	°C



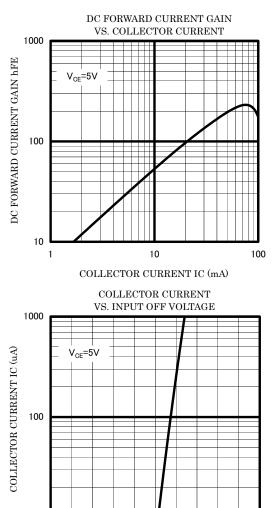
JEITA:SC-88

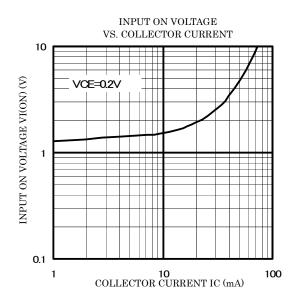
Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

ELECTRICAL CHARACTERISTICS (Ta=25°C)

Symbol	Parameter	Test conditions		Limits			Unit
				Min	Тур	Max	Unit
V(BR)CEO	Collector to Emitter break down voltage	Ic=100µ A,RBE=		50	-	-	V
Ісво	Collector cut off current	t off current V _{CB} =50V,I _E =0		-	-	0.1	μΑ
hFE	DC forward current gain VCE=5V,IC=10mA		20	-	-	-	
VCE(sat)	Collector to Emitter saturation voltage IC=10mA,IB=0.5mA		-	-	0.3	V	
VI(ON)	Input on voltage	vcE=0.2V,Ic=5mA		-	1.4	2.3	V
VI(OFF)	Input off voltage	V _{CE} =5V,I _C =100µ A		0.8	1.1	-	V
R1	Input resistor	-		3.3	4.7	6.1	k
R_2/R_1	Resistor ratio	-		0.8	1.0	1.2	-
\mathbf{f}_{T}	Gain band width product	VCE=6V,IE=10mA	RTr1	-	200	-	MHz
			RTr2	-	150	-	

TYPICAL CHARACTERISTICS (RTr1)





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0.4

0.8

1.2

INPUT OFF VOLTAGE VI(OFF) (V)

1.6

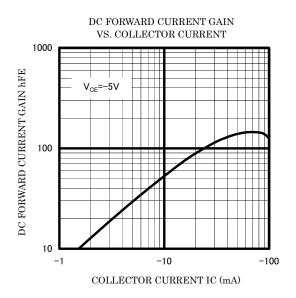
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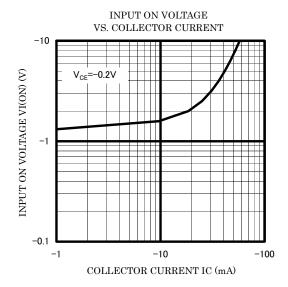
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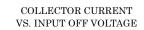
RT3TFFM

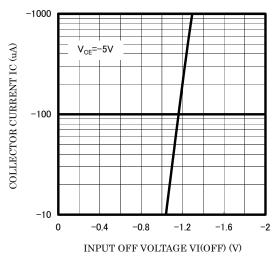
Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

TYPICAL CHARACTERISTICS (RTr2)











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